2SK1836, 2SK1837

Silicon N-Channel MOS FET

HITACHI

Application

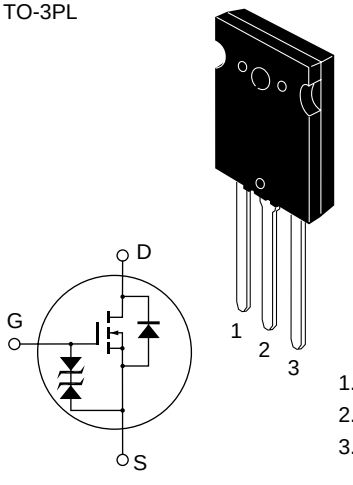
High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switchingregulator, DC-DC converter

Outline

TO-3PL



1. Gate
2. Drain (Flange)
3. Source

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Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	K1836	V_{DSS}	450	V
	K1837		500	
Gate to source voltage		V_{GSS}	±30	V
Drain current		I_D	50	A
Drain peak current		$I_{D(pulse)}$*[1]	200	A
Body to drain diode reverse drain current		I_{DR}	50	A
Channel dissipation		Pch*[2]	250	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	–55 to +150	°C

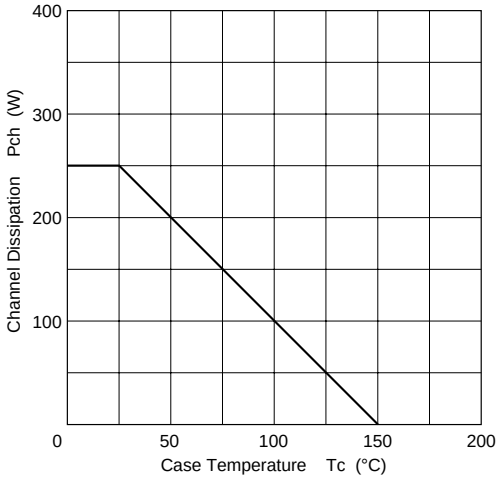
Notes 1. PW ≤ 10 µs, duty cycle ≤ 1 %
2. Value at Tc = 25 °C

Electrical Characteristics (Ta = 25°C)

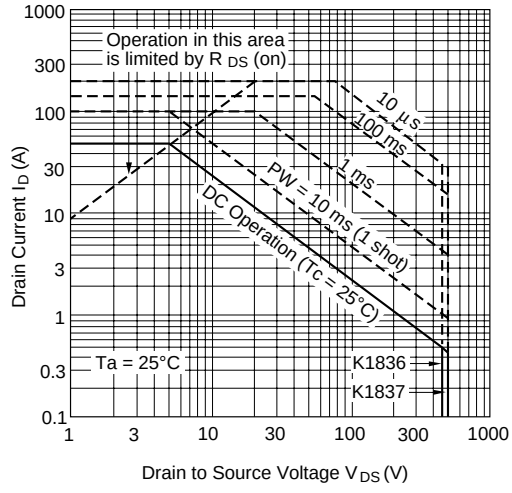
Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	K1836	$V_{(BR)DSS}$	450	—	—	V	I_D = 10 mA, V_{GS} = 0
	K1837		500	—	—		
Gate to source breakdown voltage		$V_{(BR)GSS}$	±30	—	—	V	I_G = ±100 µA, V_{DS} = 0
Gate to source leak current		I_{GSS}	—	—	±10	µA	V_{GS} = ±25 V, V_{DS} = 0
Zero gate voltage drain current	K1836	I_{DSS}	—	—	250	µA	V_{DS} = 360 V, V_{GS} = 0
	K1837						V_{DS} = 400 V, V_{GS} = 0
Gate to source cutoff voltage		$V_{GS(off)}$	2.0	—	3.0	V	I_D = 1 mA, V_{DS} = 10 V
Static drain to source on state resistance	K1836	$R_{DS(on)}$	—	0.08	0.10	Ω	I_D = 25 A
	K1837		—	0.085	0.11		V_{GS}= 10 V*[1]
Forward transfer admittance		$\|y_{fs}\|$	22	35	—	S	I_D = 25 A V_{DS} = 10 V*[1]
Input capacitance		Ciss	—	8150	—	pF	V_{DS} = 10 V
Output capacitance		Coss	—	2100	—	pF	V_{GS} = 0
Reverse transfer capacitance		Crss	—	180	—	pF	f = 1 MHz
Turn-on delay time		$t_{d(on)}$	—	80	—	ns	I_D = 25 A
Rise time		t_r	—	250	—	ns	V_{GS} = 10 V
Turn-off delay time		$t_{d(off)}$	—	550	—	ns	R_L = 1.2 Ω
Fall time		t_f	—	220	—	ns	
Body to drain diode forward voltage		V_{DF}	—	1.1	—	V	I_F = 50 A, V_{GS} = 0
Body to drain diode reverse recovery time		t_{rr}	—	620	—	ns	I_F = 50 A, V_{GS} = 0, di_F / dt = 100 A / µs

Note 1. Pulse Test

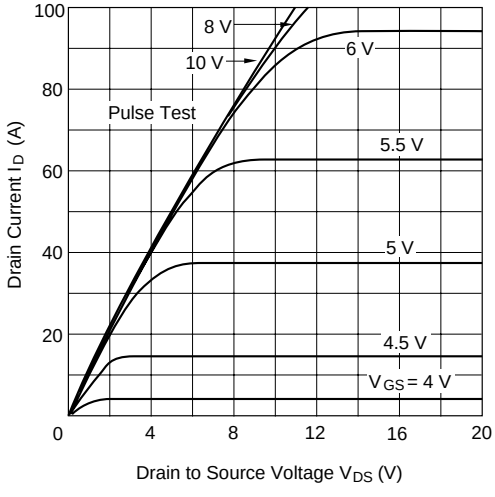
Power vs. Temperature



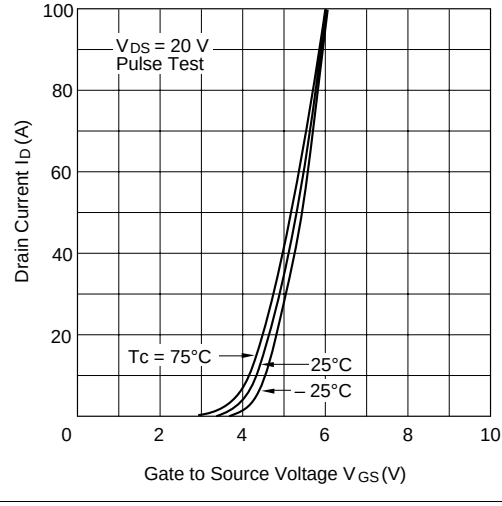
Maximum Safe Operation Area



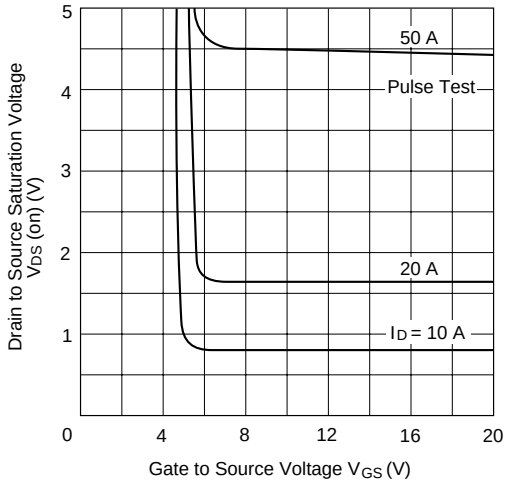
Typical Output Characteristics



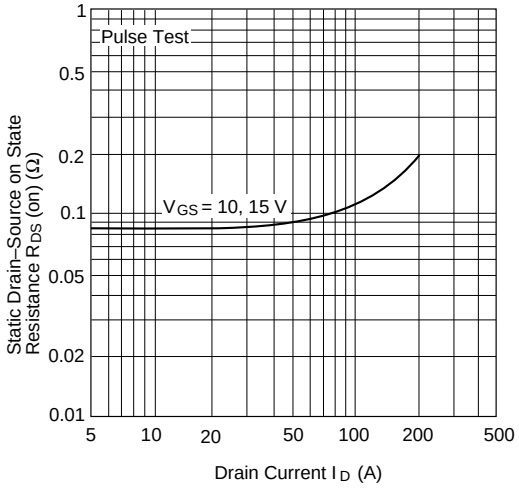
Typical Transfer Characteristics



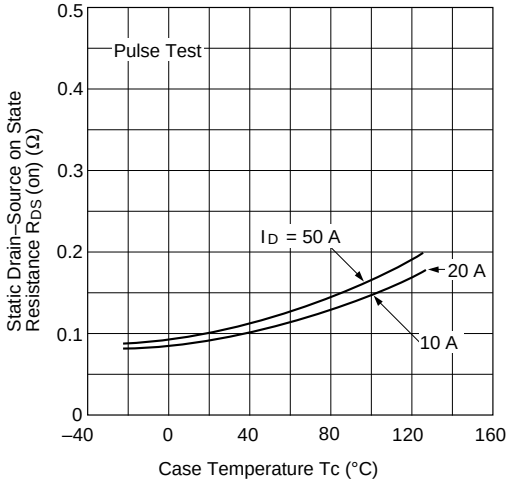
Drain to Source Saturation Voltage vs. Gate to Source Voltage



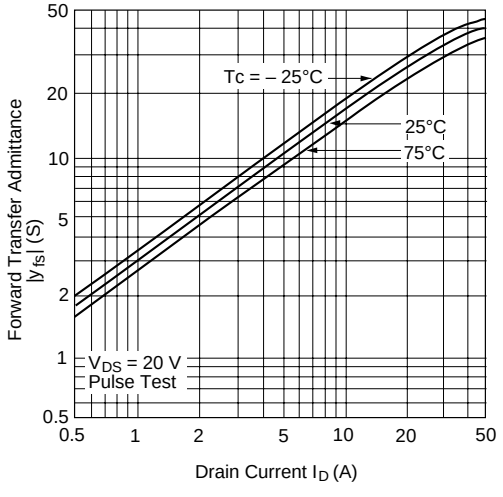
Static Drain to Source on State Resistance vs. Drain Current



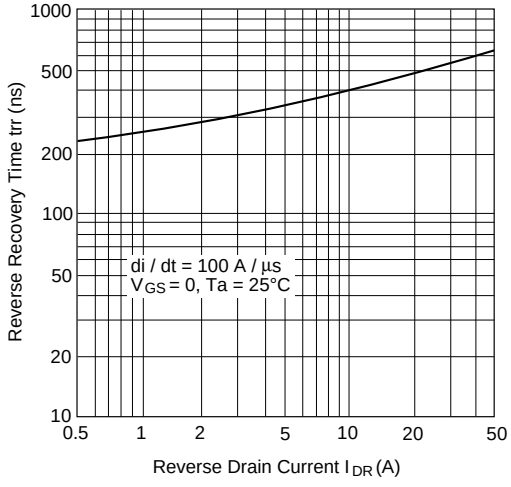
Static Drain to Source on State Resistance vs. Temperature



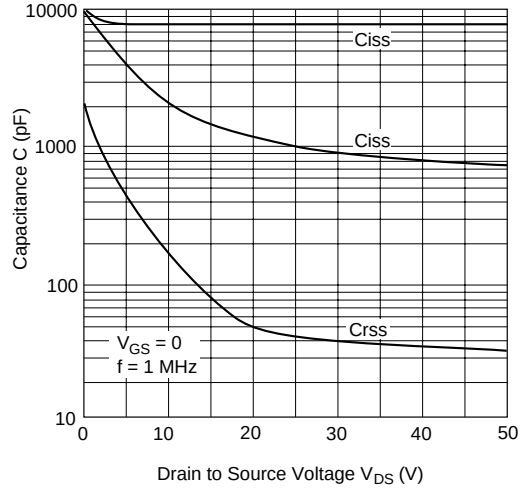
Forward Transfer Admittance vs. Drain Current



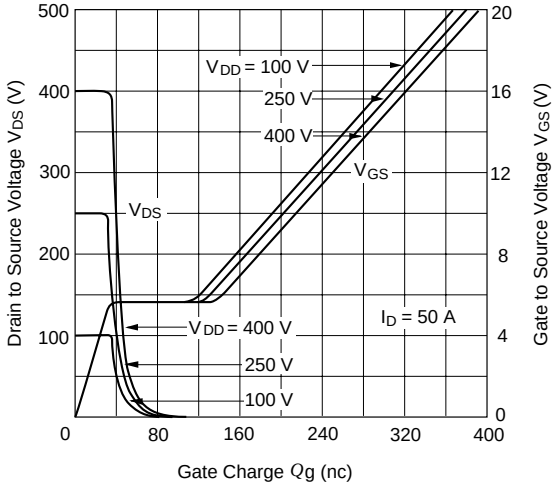
Body to Drain Diode Reverse Recovry Time



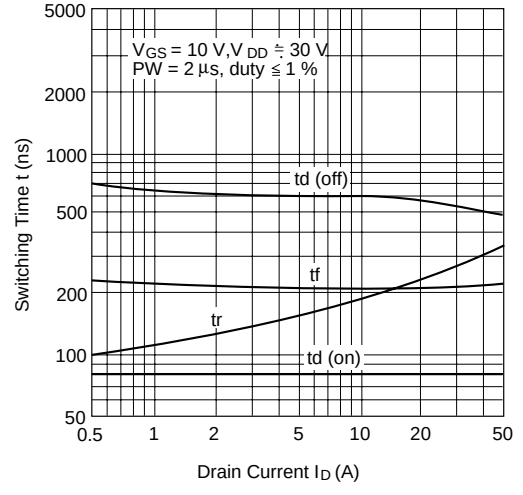
Typical Capacitance vs. Drain to Source Voltage



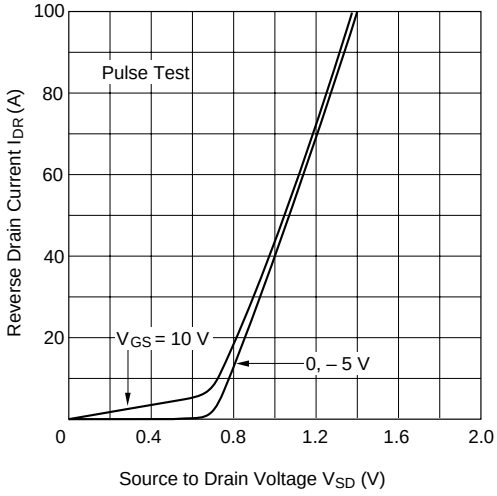
Dynamic Input Characteristics



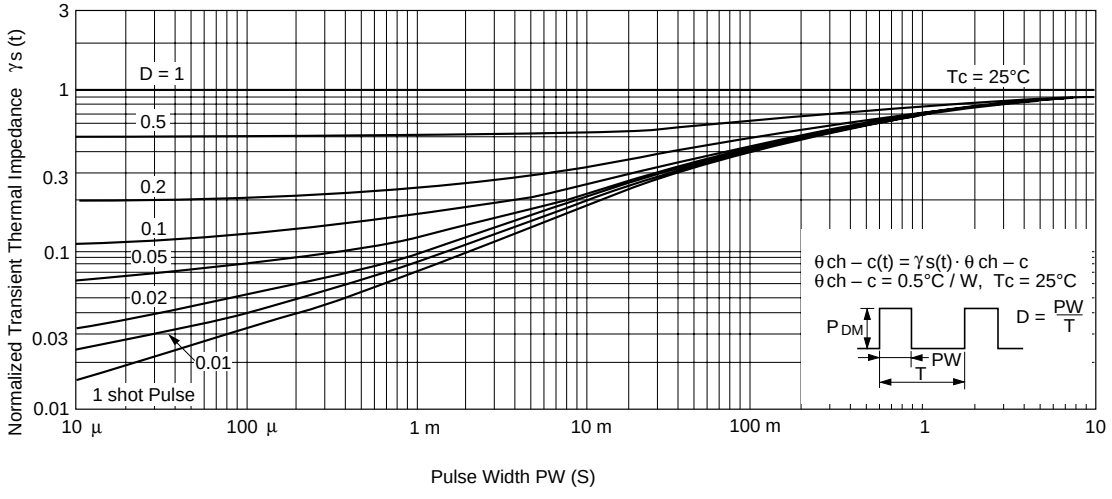
Switching Characteristics



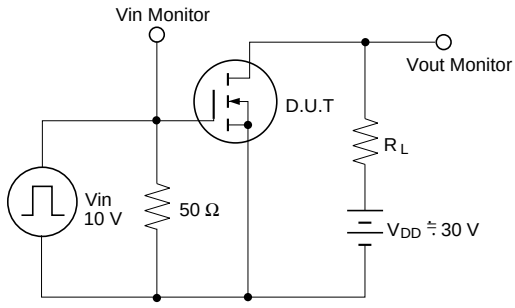
Reverse Drain Current
vs. Source Drain Voltage



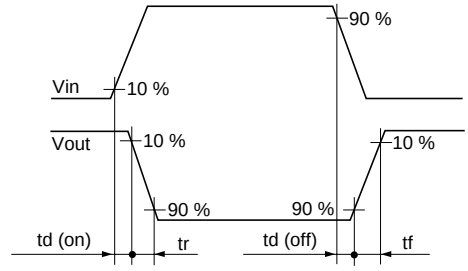
Normalized Transient Thermal Impedance vs. Pulse Width



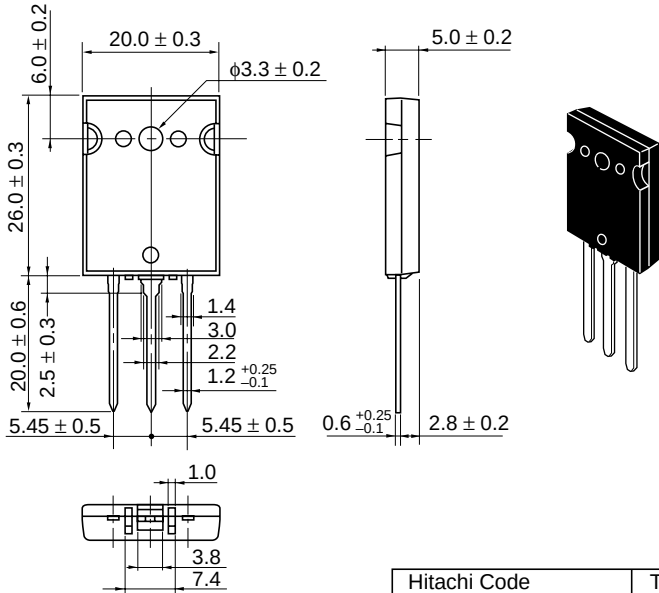
Switching Time Test Circuit



Waveforms



Unit: mm



Hitachi Code	TO-3PL
JEDEC	—
EIAJ	—
Weight (reference value)	9.9 g

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